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Substitute for form 1449A/PTO		<b>Complete If Known</b>			
<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  (use as many sheets as necessary)		Application Number	10/074,732		
		Filing Date	02/13/2002		
		First Named Inventor	Leo Mathew et al.		
		Group Art Unit	2815		
		Examiner Name	Paul E. Brock II		
Sheet	2	of	2	Attorney Docket Number	SC11805TP

**OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS**

Examiner Initials*	Cite No. 1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
	BF	YU, BIN et al.; "FinFET Scaling to 10nm Gate Length"; IEEE IEDM; 2002; pages 251-254; IEEE; USA	
	BG	International Search Report	

Examiner Signature		Date Considered	8/16/2004
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation, if not in conformance and not considered. Include copy of this form with next communication to applicant.

\* Unique citation designation number. <sup>2</sup> Applicant is to place a check mark here if English Language Translation is attached.



## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Sheet

1

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**Paul E. Brock II**

Attorney Docket Number

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**Considered**

<sup>1</sup> Unique citation designation number. <sup>2</sup> See Kinds of U.S. Patent Documents. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup> Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup> Applicant is to place a check mark here if English Language Translation is attached.



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